

BF494 NPN RF Transistor





Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

1. Collector 2. Emitter 3. Base

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	20	V
V _{CBO}	Collector-Base Voltage 30		V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	30	mA
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	- 55 ~ 150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Unit
P _D	Total Device Dissipation, by R _{θJA} Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

Electrical Characteristics* T_C = 25°C unless otherwise noted

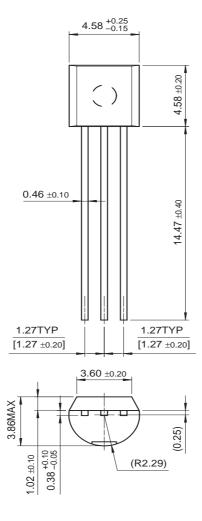
Symbol	Parameter	Conditions	Min.	Max.	Units
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_C = 1.0 \text{mA}, I_B = 0$	20		V
V _{(BR)CBO}	Collector-Base BreakdownVoltage	$I_C = 10\mu A, I_E = 0$	30		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	5.0		V
I _{CES}	Collector-Emitter Sustaining Current	$V_{CE} = 40V, V_{EB} = 0V$		10	nA
h _{FE}	DC Current Gain	$V_{CE} = 10V$, $I_C = 1mA$	67	222	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 10$ mA, $I_B = 5$ mA		0.2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 10$ mA, $I_B = 5$ mA		0.92	V
V _{BE} (ON)	Base-Emitter On Voltage	$V_{CE} = 10V, I_{C} = 10mA$	650	740	mV

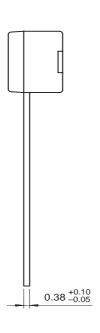
^{*} DC Item are tested by Pulse Test: Pulse Width≤300us, Duty Cycle≤2%

These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Package Dimensions

TO-92





Dimensions in Millimeters

UltraFET®

UniFET™

 VCX^{TM}

Wire™

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Definition of Terms

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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